

A Low-Cost and Accurate Interface for Four-Electrode Conductivity Sensors

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Abstract—This paper presents a low-cost and accurate interface for four-electrode conductivity sensors. The interface mainly consists of an analog front-end, a multiplexer, and a voltage-to-time converter. The analog front-end is used to provide a controlled excitation voltage for the sensor and to convert the sensor signal (conductance) into a voltage signal. The voltage-to-time period converter acts as an asynchronous converter for the sensor signals (voltage), which employs a relaxation oscillator and outputs a period-modulated signal. Experimental results over a conductance range of $0.1 \mu\text{S}$ to 20 mS show a random error of 1.6×10^{-5} and a systematic error of 6.6×10^{-5} for a measurement time of 110 ms.

Index Terms—Conductivity measurement, oscillators, sensors.

I. INTRODUCTION

CONDUCTIVITY sensors are required in many application fields, including medical and biomedical fields, process chemistry, environment monitoring, agriculture and food production, etc. [1]–[4]. The accuracy and resolution of conductance measurements depend on chemical, physical, and electrical nonidealities. Regarding the chemical and physical effects, the main nonidealities concern:

- contamination of the electrode surface of the sensor;
- electrochemical effects;
- temperature dependence.

Considering the electrical effects, the main nonidealities concern:

- series impedances caused by the wires and cables, used to connect the conductivity sensor to the sensor electronics;
- effects of the dc drift and the influence of parasitic Seebeck voltages;
- effects of offset, $1/f$ noise, and low-frequency interference;
- effects of multiplicative and additive errors of the processing circuit.

To overcome those nonidealities, in this paper a low-cost and accurate interface for four-electrode conductivity sensors is proposed, in which many advanced techniques are applied. These techniques include four-wire measurement, ac square-wave excitations, chopping [6], and autocalibration.

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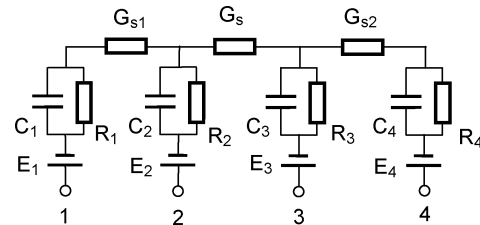


Fig. 1. A simple electrical model of the four-electrode conductivity sensor.

II. MEASUREMENT PRINCIPLE

A. Model and Measurement of the Conductivity Sensor

Fig. 1 shows a simple electrical model of a four-electrode conductivity sensor. In this model, the symbol G_s represents the conductance of the object, which should be measured by the conductivity sensor. The components $R_1 \sim R_4$ and $C_1 \sim C_4$ model the electrical behavior of the electrode-object interface. The potentials $E_1 \sim E_4$ represent the contact potentials. The values of these potentials depend on the materials of the electrode and the object. Generally, they are not equal, nor are they stable. The components G_{s1} and G_{s2} represent the conductance path through the object between the force and sense electrodes of the sensor. To measure the conductance G_s accurately, the influence of these parasitics should be eliminated or significantly reduced.

The effect of the contact potentials on the measurement of the G_s can be eliminated by using an ac excitation signal for the sensor. To eliminate the effect of the impedances $R_1 \sim R_4$, G_{s1} and G_{s2} as well as the effect of the lead-wire resistance, a four-wire measurement is applied. Fig. 2(a) shows a simplified diagram of the four-wire measurement method. In this measurement, the four-electrode sensor is excited with a constant ac current source I_{ex} . The voltage over the sensor conductance G_s is measured with an electronic circuit with high input-impedance. In this measurement, when the measured conductance G_s is low, the voltage over G_s can be very high due to the use of the constant-current excitation signal. This will result in a measurement, which is out of the linear range. Moreover, the voltage between the electrodes 2 and 3 will exceed the free corroding potential.

To overcome this drawback, the conductance G_s can be measured using a constant ac voltage excitation V_{ex} [see Fig. 2(b)] [5]. In this circuit, the voltage V_{Gs} over the conductance is fixed to the value of V_{ex} by the feedback loop around the amplifiers A_1 and A_2 . In case of ideal amplifiers that have a very high loop gain, a negligible input current, and offset voltage, the voltage

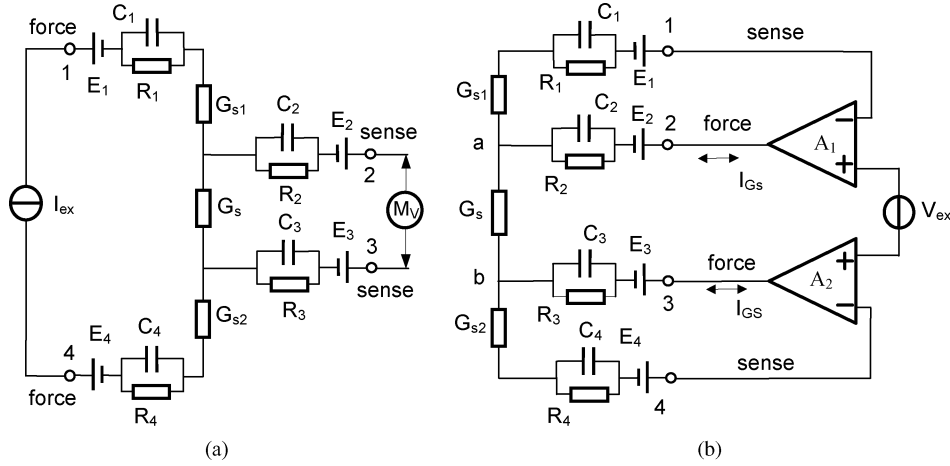


Fig. 2. Four-wire measurement of the four-electrode conductivity sensor: (a) constant-current excitation and (b) constant-voltage excitation.

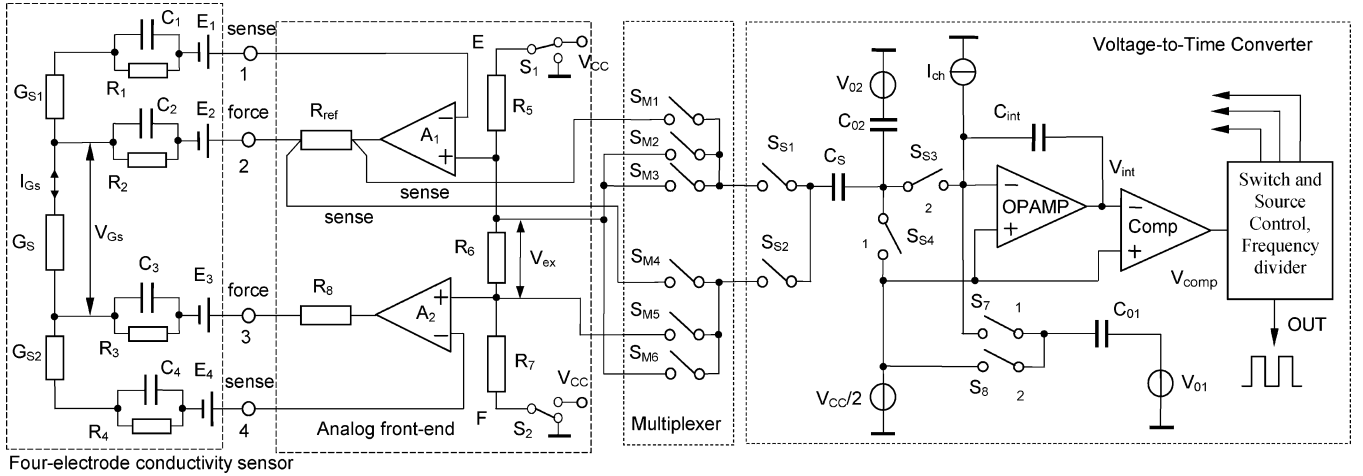


Fig. 3. Simplified interface for the conductance measurement.

V_{Gs} over the conductance G_s equals V_{ex} . Therefore, the measured conductance equals

$$G_s = \frac{I_{Gs}}{V_{Gs}} = \frac{I_{Gs}}{V_{ex}}. \quad (1)$$

So, for a constant voltage V_{ex} , the current flow I_{Gs} is proportional with the measured conductance.

The described measurement method for the sensor conductance G_s concerns a so-called four-wire method, in which force and sense wires are applied. Such a method reduces the effect of series impedances of the wires and cables that connect the conductivity sensor to the electronic circuit. Meanwhile, the effect of the deposits on the electrode surface of conductivity sensor is reduced as well.

B. Circuit Diagram of the Interface

Fig. 3 shows a simplified schematic diagram of the interface, which mainly consists of an analog front-end, a multiplexer, and a voltage-to-time converter.

As shown in the above section, in the analog front-end circuit two amplifiers in a unity-gain configuration are employed to establish a controlled excitation voltage V_{Gs} across the measured conductance G_s . The voltage V_{Gs} is equal to the voltage V_{ex} across the resistor R_6 . To avoid electrolysis, this voltage should

be less than the free corroding potential. The current flow I_{Gs} , which is equal to the current through the resistor R_{ref} or R_8 , is measured by measuring the voltage V_{Rref} across the resistor R_{ref} . Both voltages V_{ex} and V_{Rref} are directly measured using the voltage-to-time converter via the multiplexer.

The voltage-to-time converter linearly converts the sensor signal (voltage) and the reference signal (voltage) into period-modulated signals by employing a first-order charge-balanced oscillator. The multiplexer, which is formed using six analog switches $S_{M1} \sim S_{M6}$, selects the signal to be measured V_{ex} , V_{Rref} , or V_{COM} , where V_{COM} is the offset measurement. The capacitor C_s with two switches S_{s1} and S_{s2} samples one of these three voltages. The charge is dumped into the integrator capacitor C_{int} . The current I_{ch} is periodically integrated and this results in periodic signals.

An ac square-wave excitation signal is generated by using switches S_1 and S_2 . The use of ac signals is important to reduce electrochemical effects and the effects of dc drift and parasitic Seebeck voltages. Meanwhile, the ac square-wave excitation signal is also used to implement advanced chopping [6], [7], synchronized with voltage-to-time conversion. The chopping technique significantly reduces the effects of offset, $1/f$ noise, and low-frequency interference. This enables the use of low-cost CMOS technology for accurate measurement systems.

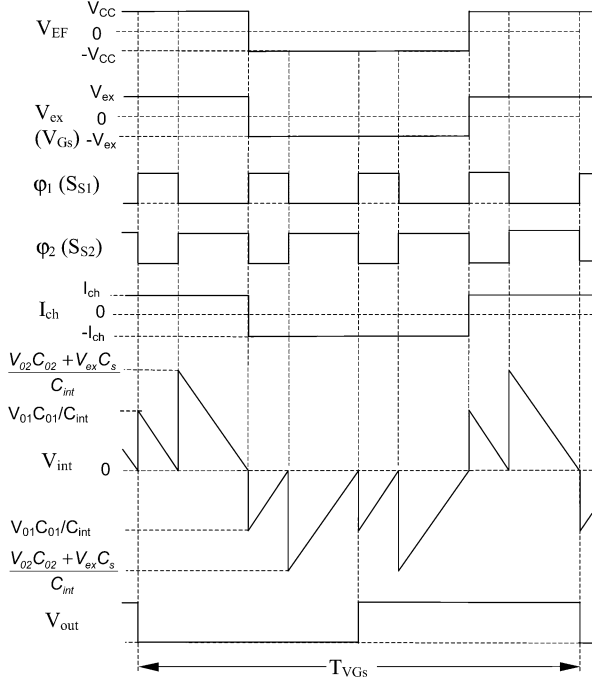


Fig. 4. Some relevant signal levels and control signals in the voltage-to-time converter when the voltage signal V_{ex} is measured.

Let us suppose that, for example, the voltage V_{ex} has to be converted into the time domain. Fig. 4 shows some relevant signal levels and control signals in the voltage-to-time converter.

In one complete cycle for the measurement of voltage signal V_{ex} , four measurements are included, which have a chopping sequence of $+-+ +, +- -, \dots$. The application of such chopping technique eliminates the effect of nonidealities of amplifiers A_1 and A_2 and the effect of the contact potentials $E_1 \sim E_4$, as well as the offset effect of the interface and the effect of any other low-frequency signals.

The use of C_{01} measurement ensures a proper sample-and-hold action of the oscillator [6].

As presented in [6] and [7], the periods of the output signal of the oscillator T_{VGs} , T_{IGs} , and T_{off} , corresponding to the measurement of V_{ex} , V_{Rref} , and V_{COM} , are given by the equations

$$\begin{aligned} T_{VGs} &= 4 \frac{V_{ex}C_s}{I_{ch}} + 4 \frac{V_0(C_{01} + C_{02})}{I_{ch}} \\ T_{IGs} &= 4 \frac{V_{Rref}C_s}{I_{ch}} + 4 \frac{V_0(C_{01} + C_{02})}{I_{ch}} \\ T_{off} &= 4 \frac{V_0(C_{01} + C_{02})}{I_{ch}}. \end{aligned} \quad (2)$$

Using these three measurements, the measured result for the conductance of the conductivity sensor is found by the equation

$$G_s = \frac{T_{IGs} - T_{off}}{T_{VGs} - T_{off}} \cdot \frac{1}{R_{ref}}. \quad (3)$$

This result does not depend on the unknown offset and the unknown transfer factor of the interface. In this way, the interface is autocalibrated for additive or multiplicative errors. Even in the case of slow variations of the offset and transfer factor,

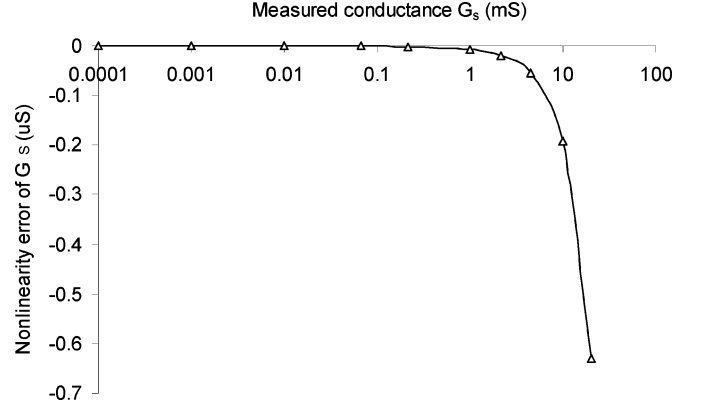


Fig. 5. Nonlinearity errors due to the finite dc gain of amplifiers.

these effects are eliminated. The algorithm can be implemented using, for instance, a microcontroller.

III. NONIDEALITIES

As described in Section II, many nonidealities of the interface are eliminated by means of the autocalibration technique [(3)]. However, some effects cannot be eliminated by this technique and should be taken into account during the design of this interface.

A. Finite DC Gain of Op-Amps A_1 and A_2

The finite dc gains of the amplifiers A_1 and A_2 shown in Fig. 3 cause a nonlinearity error in the measurement of conductance G_s . When both amplifiers A_1 and A_2 have a dc gain A_0 , the nonlinearity error ε_{gain} caused by the finite dc gain is given by

$$\varepsilon_{gain} = G_{sm} - G_s = - \frac{1 + (R_8 + R_{ref})G_s}{1 + A_0 + (R_8 + R_{ref})G_s} G_s \quad (4)$$

where G_{sm} is the measured conductance according to (3) and G_s is the conductance to be measured.

Example: When the dc gain of both amplifiers A_1 and A_2 is 104 dB and $R_{ref} = R_8 = 100 \Omega$, the nonlinearity error due to the finite dc gain of amplifiers is as shown in Fig. 5.

The effect of the contact resistors R_2 and R_3 on the linearity is similar to the effect of resistors R_{ref} and R_8 . To calculate this effect, the resistor values in (4) have to be increased by the values of the corresponding contact resistances

B. Contact Potentials $E_1 \sim E_4$

Due to the contact potentials $E_1 \sim E_4$ and the finite dc gain of the amplifiers A_1 and A_2 , the voltage V_{Gs} over the measured conductance amounts to

$$V_{Gs} = \frac{A_0}{1 + A_0} V_{ex} - \frac{A_0}{1 + A_0} (E_1 - E_4) - \frac{E_2 - E_3}{1 + A_0}. \quad (5)$$

It is shown that the contact potentials $E_1 \sim E_4$ cause an additional offset on the voltage over the measured conductance. When the bandwidth of these contact potentials is much less than that of the excitation signal (chopping frequency), this offset will be eliminated by applying the chopping technique as described in the Section II.

C. Input Offset Voltage V_{os} and Biasing Current I_{bias} of Op-Amps A_1 and A_2

The input offset voltages V_{os} of the amplifiers A_1 and A_2 have a similar effect as the contact potentials E_1 and E_4 . When the bandwidth of the input offset voltages is much less than that of the excitation signal (chopping frequency), their effects will be eliminated by the applied chopping technique.

The biasing currents I_{Bias1} and I_{Bias2} of the amplifiers A_1 and A_2 affect not only the measurement of the current I_{Gs} but, due to the presence of resistive components R_1 , R_4 , G_{S1} , and G_{S2} , also the measurement of the voltage V_{Gs} . However, these nonidealities cause only additional offsets in the measurements of the current I_{Gs} and the voltage V_{Gs} , according to the set of equations

$$\begin{aligned} V_{Gs} &= V_{ex} + I_{Bias1} \left(R_1 - \frac{1}{G_{S1}} \right) - I_{Bias2} \left(R_4 - \frac{1}{G_{S2}} \right) \\ I_{Gs} &= \frac{V_{Rref}}{R_{ref}} + I_{Bias1}. \end{aligned} \quad (6)$$

If the bandwidth of the input biasing currents is much less than that of the excitation signal (chopping frequency), these offsets will be eliminated by the applied chopping technique.

D. The ON-Resistor R_{ON} of Sampling Switches

The ON-resistors $R_{ON,S}$ and $R_{ON,M}$ of sampling switches S_{S1} or S_{S2} and multiplexer switches $S_{M1} \sim S_{M6}$, together with R_5 , R_6 , R_7 , and R_{ref} and the capacitances associated with these resistors, form an RC circuit. For instance, when the voltage V_{ex} is measured, the time constant of this RC circuit is

$$\tau_i = (R_5 // (R_7 + R_6) + R_{ON,M} + R_{ON,S}) (C_s + C_p) \quad (7)$$

where C_p is the parasitic capacitance. This time constant τ_i results in a relative error for the result

$$\epsilon_{NL} = \exp \left(-\frac{T_p}{\tau_i} \right) \quad (8)$$

where T_p is the minimum time period of the voltage-to-time converter.

Example: When the minimum time period T_p is 10 μ s, $R_5 = R_7 = 5$ k Ω , $R_6 = 200$ Ω , $R_{ON,M} = R_{ON,S} = 1$ k Ω , $C_p = 50$ pF, and $C_s = 28$ pF, the relative error due to the time constant ϵ_{NL} amounts to 3×10^{-9} .

E. Temperature Drift

As described in Section II, the offset and gain errors of the interface are eliminated by applying the autocalibration (3). This autocalibration will also eliminate the drift of the offset and gain of the interface due to the temperature variations. Yet, the reference resistor R_{ref} should have a low temperature coefficient because its temperature performance will directly affect the absolute measurement result of the conductance G_s [see (3)].

IV. EXPERIMENTAL RESULTS

The proposed sensor interface has been implemented and tested using the circuit shown in Fig. 3. For the operational amplifiers, a dual op-amp (OPA2132PA) has been

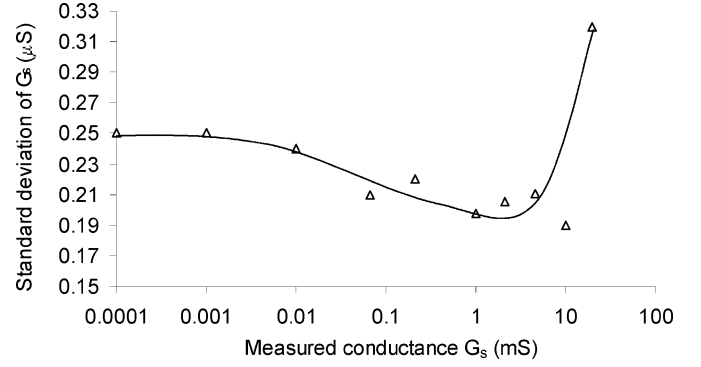


Fig. 6. The standard deviation of the random error of the conductance measurement for a measurement time of 110 ms.

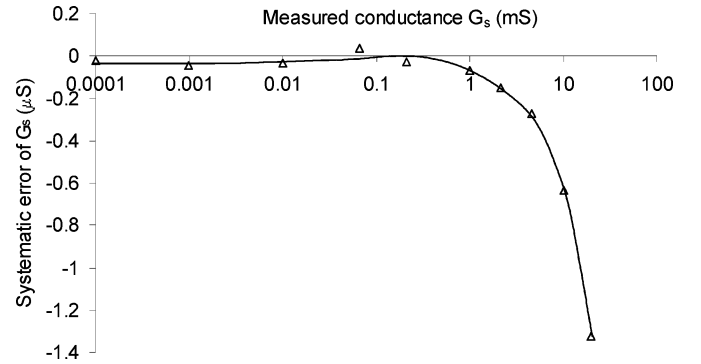


Fig. 7. Systematic error of the interface. Each of the plotted data points represents the average of 100 measurement results.

used. The voltage-to-time converter and multiplexer have been implemented with a universal transducer-interface chip (UTI03-A79C), which has been realized using low-cost CMOS technology [8]. The ac square-wave excitation signal is generated by the voltage-to-time converter itself. The frequency of the excitation signal amounts to 7 kHz \sim 12.5 kHz depending on the value of measured conductance. A microcontroller of the type PIC16F876, which has a 5 MHz counting frequency, is employed to measure the output period of the voltage-to-time converter. It also processes the data and communicates with the outside digital world. The system is powered by a single 5 V supply voltage.

The performances of the interface have been tested for the case that $R_{ref} = 100.076$ Ω with a temperature coefficient of 10^{-6} /K and $G_s = 0.1$ μ S to 20 mS, with a measurement time of about 110 ms. The controlled excitation voltage V_{ex} has been applied with a peak-to-peak value of 200 mV. Depending on the electrochemical properties, the amplitude of the excitation signal can be adjusted for a value less than the free corroding potential. The main measurement results for the conductance G_s are depicted in Figs. 6 and 7, which show the standard deviation of the random error and the systematic error, respectively. The standard deviation has been derived for a large number of measurements, each with a measurement time of 110 ms. When determining the systematic error (Fig. 7), the effect of the random error has been reduced by taking the average of 100 measurements for each data point plotted in the figure.

It is shown that the interface has a standard deviation of 1.6×10^{-5} ($0.32 \mu\text{S}$) and a systematic error of 6.6×10^{-5} ($1.32 \mu\text{S}$) over a conductance range of $0.1 \mu\text{S}$ to 20 mS and a measurement time of about 110 ms . Two successive measurements over a conductance range of $0.1 \mu\text{S}$ to 20 mS have been performed, which show that the repeatability of the interface amounts to $0.18 \mu\text{S}$.

Fig. 7 shows that the systematic error increases with increasing conductance G_s . As discussed in Section III, this is due to the finite dc gain of the amplifier A_1 and A_2 .

V. CONCLUSIONS

In this paper, an interface for conductivity sensors has been presented. A low-cost interface with a high accuracy and good long-term stability has been realized by applying advanced measurement techniques including four-wire measurement technique, ac square-wave excitation, chopping and autocalibration. The controllable excitation signal for conductivity sensors enables avoiding the electrolysis. Tests have been performed over the conductance range of $0.1 \mu\text{S}$ to 20 mS . It is shown that, with a measurement time of about 110 ms , the interface can measure the conductance with a standard deviation of 1.6×10^{-5} and a systematic error of 6.6×10^{-5} . The proposed interface is very suitable for implementation in low-cost CMOS technology.

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